

INTERNATIONAL ELECTROTECHNICAL COMMISSION IEC Certification Scheme for Explosive Atmospheres

for rules and details of the IECEx Scheme visit www.iecex.com

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IECEx BVS 04.0002U

issue No.:2

Certificate history:

Status:

Current

Issue No. 2 (2014-1-30) Issue No. 1 (2007-6-21) Issue No. 0 (2004-2-13)

Date of Issue:

2014-01-30

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Applicant:

Micro Motion, Inc. 7070 Winchester Circle Boulder, CO 80301 United States of America

Electrical Apparatus:

Signal processing device type 700

Optional accessory:

Type of Protection:

Equipment protection by intrinsic safety "i"

Marking:

Ex ib IIB/IIC Gb

Approved for issue on behalf of the IECEx

Certification Body:

Dr. F. Eickhoff

Position:

Deputy Head of Certification Body

Signature:

(for printed version)

Date:

2014-01-30

1. This certificate and schedule may only be reproduced in full.

2. This certificate is not transferable and remains the property of the issuing body.

3. The Status and authenticity of this certificate may be verified by visiting the Official IECEx Website.

Certificate issued by:

DEKRA EXAM GmbH Dinnendahlstrasse 9 44809 Bochum Germany





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Micro Motion, Inc. Manufacturer:

7070 Winchester Circle Boulder, CO 80301

United States of America

Additional Manufacturing location

Emerson Process Management Flow Technologies Co., Ltd. 111, Xing Min South Road, Jiangning, Nanjing,

Jiangsu Province 211100 China

Micro Motion, Inc. Ave. Miguel de Cervantes 111 Management Flow B.V.

Complejo Industrial Chihuahua 31109 Mexico

Emerson Process Neonstraat 1

6718 WX Ede The Netherlands

This certificate is issued as verification that a sample(s), representative of production, was assessed and tested and found to comply with the IEC Standard list below and that the manufacturer's quality system, relating to the Ex products covered by this certificate, was assessed and found to comply with the IECEx Quality system requirements. This certificate is granted subject to the conditions as set out in IECEx Scheme Rules, IECEx 02 and Operational Documents as amended.

STANDARDS:

The electrical apparatus and any acceptable variations to it specified in the schedule of this certificate and the identified documents, was found to comply with the following standards:

Explosive atmospheres - Part 0: General requirements IEC 60079-0: 2011

Edition: 6.0

IEC 60079-11: 2011

Edition: 6.0

Explosive atmospheres - Part 11: Equipment protection by intrinsic safety "i"

This Certificate does not indicate compliance with electrical safety and performance requirements other than those expressly included in the Standards listed above.

TEST & ASSESSMENT REPORTS:

A sample(s) of the equipment listed has successfully met the examination and test requirements as recorded in

IECEx ATR: DE/BVS/04/2012/N1 NO/DNV/QAR07.0003/04

NO/DNV/QAR08.0005/03

File Reference:

DE/BVS/ExTR06.0006/01 NO/DNV/QAR07.0008/04 NO/DNV/QAR07.0002/04



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Schedule

EQUIPMENT:

Equipment and systems covered by this certificate are as follows:

The signal processing device is used for the connection of sensors to transmitters.

The electrical components are completely encapsulated in a plastic housing. On the top of the housing terminals for the connection of the circuits from / to the transmitter are situated and the connection of the sensor is by means of a 9 pin connector at the bottom.

Marking
The name of the manufacturer or his trademark Type 700 Ex ib IIB/IIC Gb Serial number Certificate number

Schedules of limitation

- The signal processing device has to be mounted inside an enclosure degree of protection min. IP20 in accordance with IEC 60529.
- The installation of the signal processing device inside an enclosure has to be done in a way that the clearances between the connection facilities and earthed metal parts are min. 3 mm.
- The signal processing device is designed for use in a temperature range of -40 °C to +60 °C; the max. temperature rise (selective at the surface of the plastic enclosure) is \leq 35 K.

CONDITIONS OF CERTIFICATION: NO

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EQUIPMENT(continued):

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Para	<u>meters</u>		
1	Input circuit (terminals 1 - 4) Voltage Current Power Effective internal capacitance Effective internal inductance	U _i DC I _i P _i C ⁱ L _i	17.3 V 484 mA 2.1 W 2200 pF 30 µH
2	Output (sensor) circuits		
2.1	Drive circuit (pins 7 - 8) Voltage Current Power Internal resistance	U _o DC I _o P _o R _i	10.5 V 2.45 A 2.54 W 4.32 Ω
	For group IIC Max. external capacitance Max. external inductance Max. external inductance/resistance ratio	C _o L _o L _o /R _o	2.41 μF 5.9 μH 5.5 μH/Ω
	For group IIB Max. external capacitance Max. external inductance Max. external inductance/resistance ratio	C _o L _o L _o /R _o	16.8 μF 24 μH 22 μH/Ω
2.2	Pick-off circuits (pins 3up to 6) Voltage Current Power	U _o DC I _o P _o	17.3 V 6.9 mA 30 mW
	For group IIC Max. external capacitance Max. external inductance Max. external inductance/resistance ratio	C _o L _o L _o /R _o	353 nF 742 mH 1.19 mH/Ω
	For group IIB Max. external capacitance Max. external inductance Max. external inductance/resistance ratio	C _o L _o L _o /R _o	2.06 μF 2.97 H 4.75 mH/Ω

To be continued on page 6



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DETAILS OF CERTIFICATE CHANGES (for issues 1 and above):

The device has been assessed in acc. with the current standard versions; a new marking is the result. A new manufacturing location has been added.



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Additional information:

2.3	Temper	ature	circuit	(pins	1,	2 and 9	9)
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Voltage	Uo	DC '	17.3	V	
Current	I _o	2	26	mA	
Power	P_o	1	12	mW	
For group IIC					
Max. external capacitance	Co	3	53	nF	
Max. external inductance	L_{o}	5	52.6	mH	
Max. external inductance/resistance ratio	L _o /R _o		0.32	mH/Ω	
For group IIB					
Max. external capacitance	C_{o}		2.06	μF	
Max external inductance	L	2	10	mH	

Ambient temperature range (temperature at mounting place) T_a
Max. temperature rise

Max. external inductance/resistance ratio

-40 °C up to +60 °C

 mH/Ω

35 K

1.26